

Supplementary materials

Title: Aggregation and conductivity in hot-grown petroporphyrin films

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Figure S1

EAS of copper etioporphyrin films deposited on cold/hot substrate (standard ITO coated glass slides from Sigma-Aldrich)

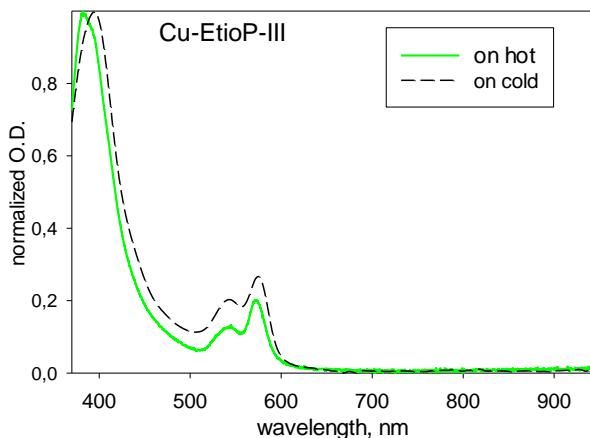
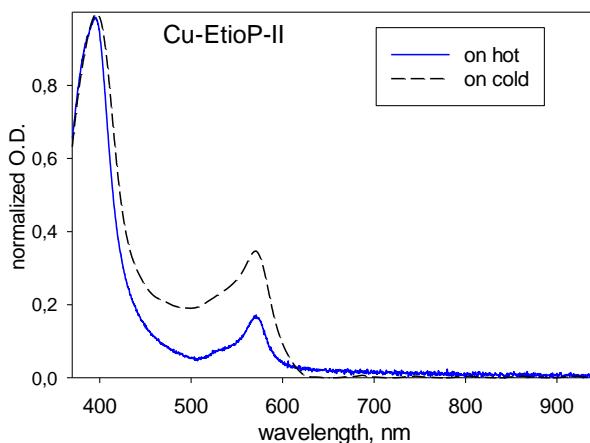
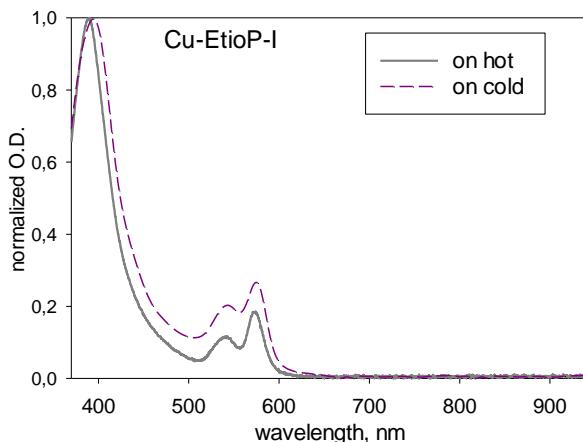


Figure S2

Comparison of SEM (top b/w panels, see Fig. 2) and AFM (bottom color panels) images of the surface of hot-grown Cu-etioporphyrin films on silicon wafer

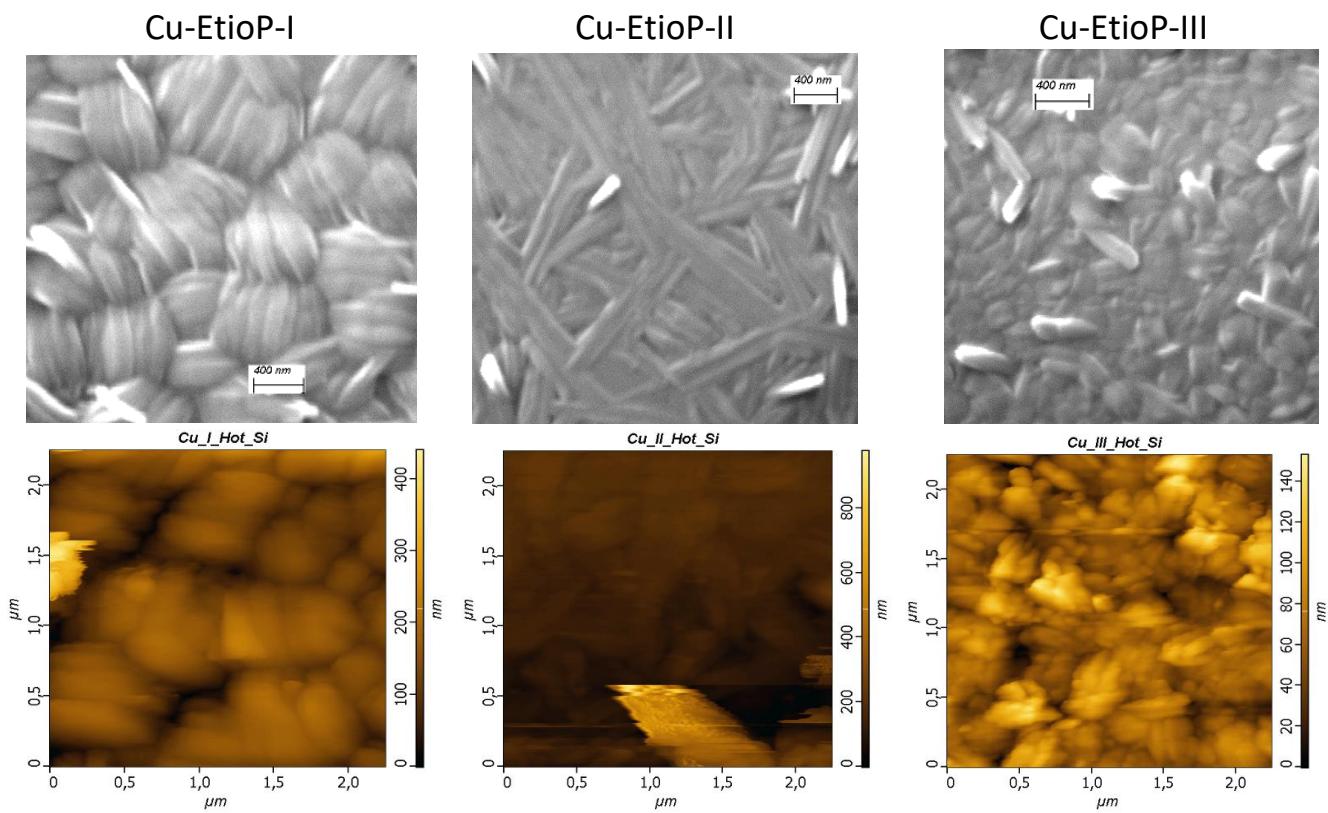
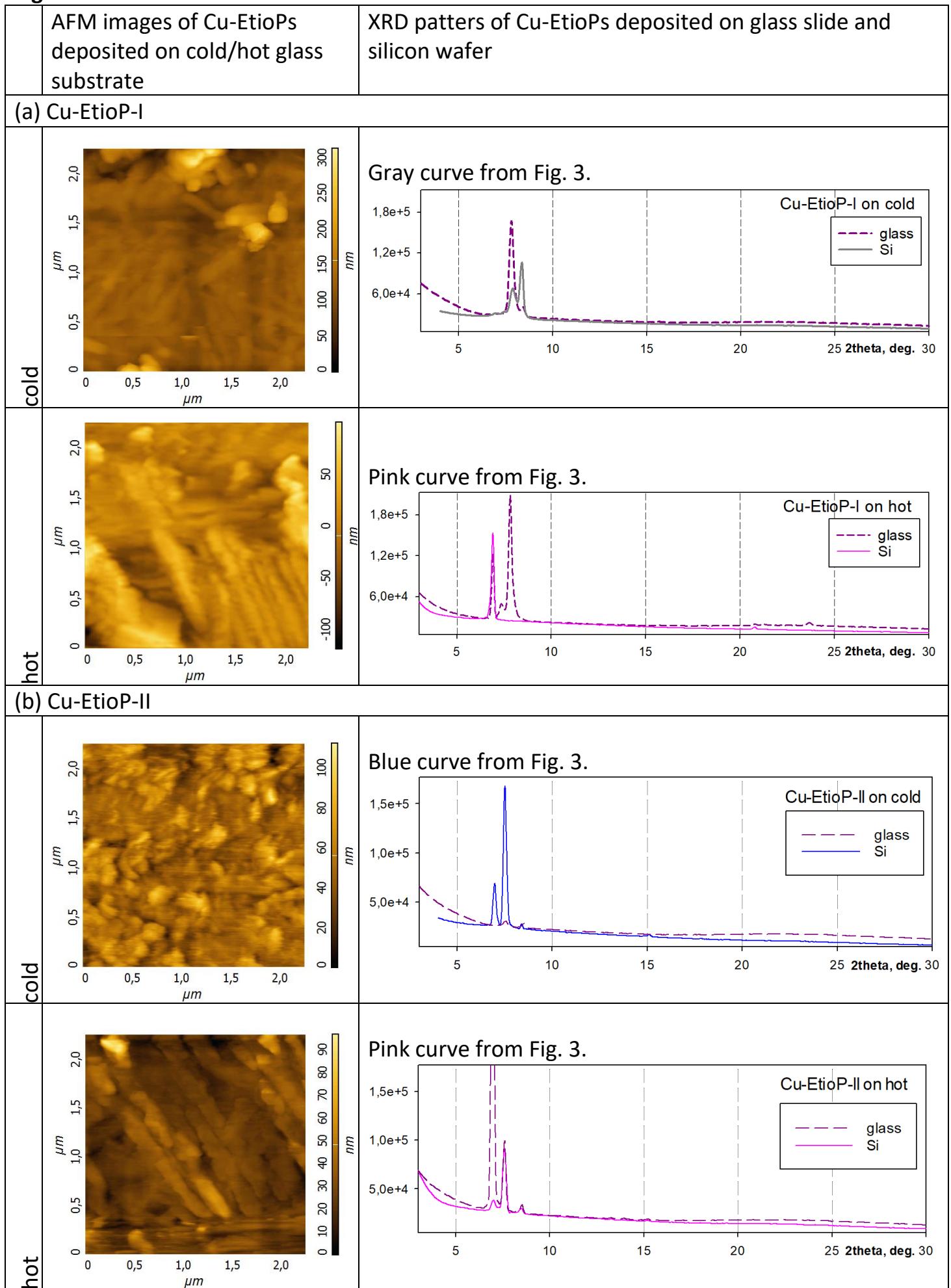
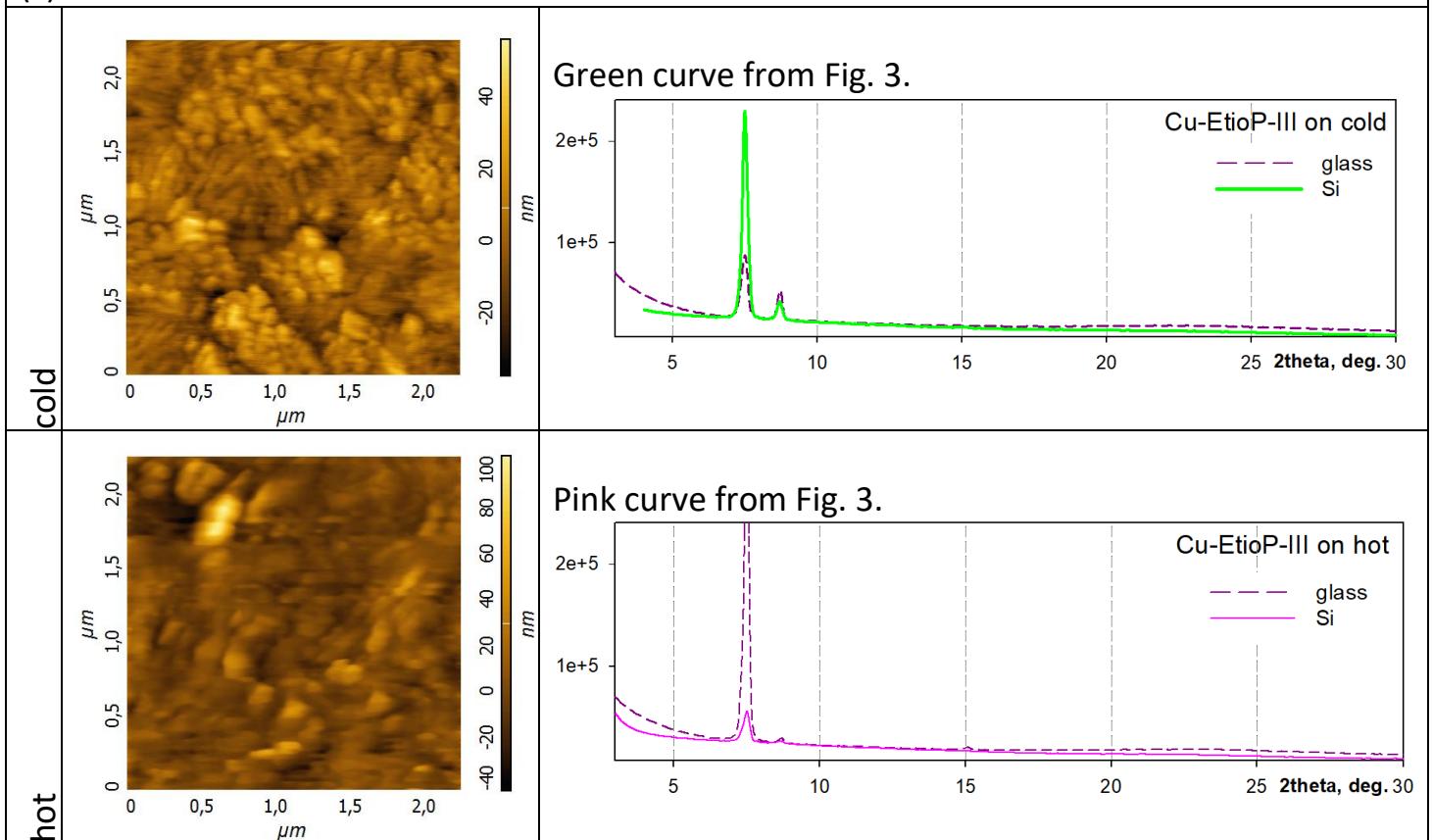


Figure S3

(c) Cu-EtioP-III

**Figure S4**

The XRD-patterns of Cu-EtioP-II films deposited either by drop-casting from the binary solution (toluene+DMF) or by vacuum evaporation on hot substrate, compared to the powder spectrum

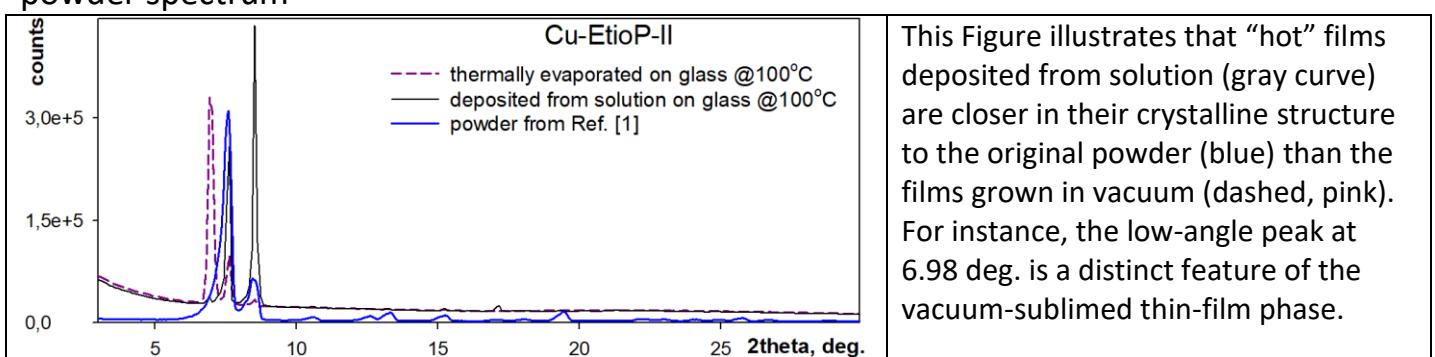


Figure S5

AFM images of the surface of Cu-etioporphyrin-I films grown on various substrates at $T_g = \text{cold}$

silicon wafer

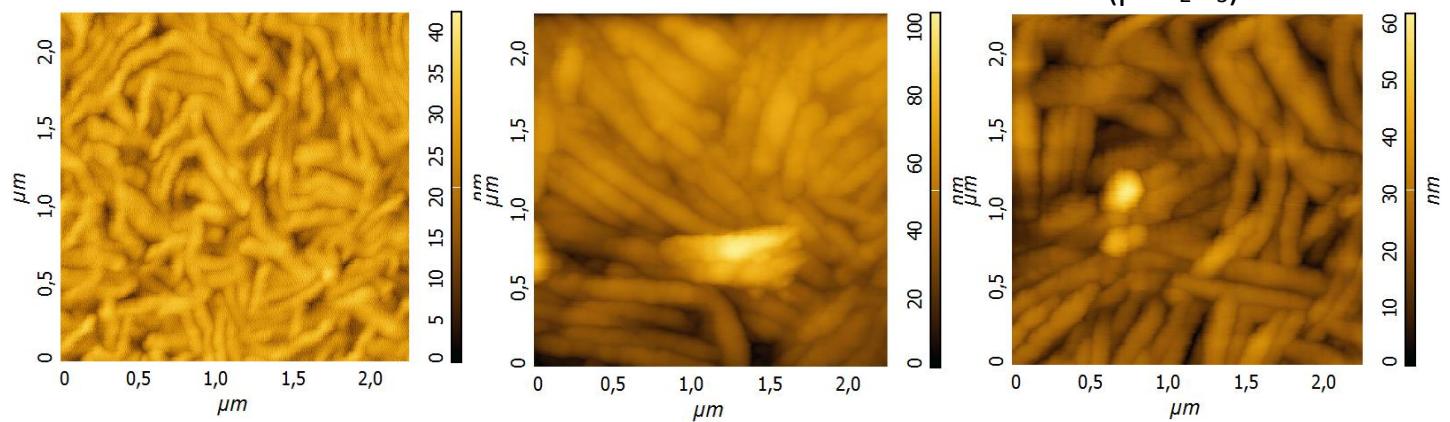


Figure S6

Photo of Cu-EtioP-I film vacuum-deposited on the IDE substrate

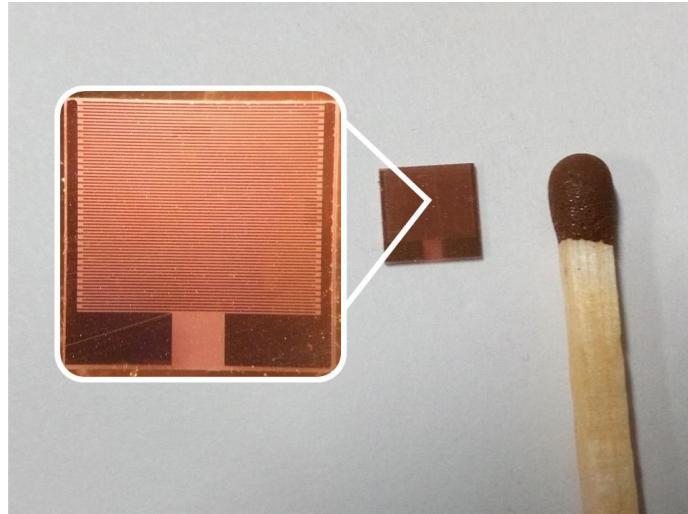
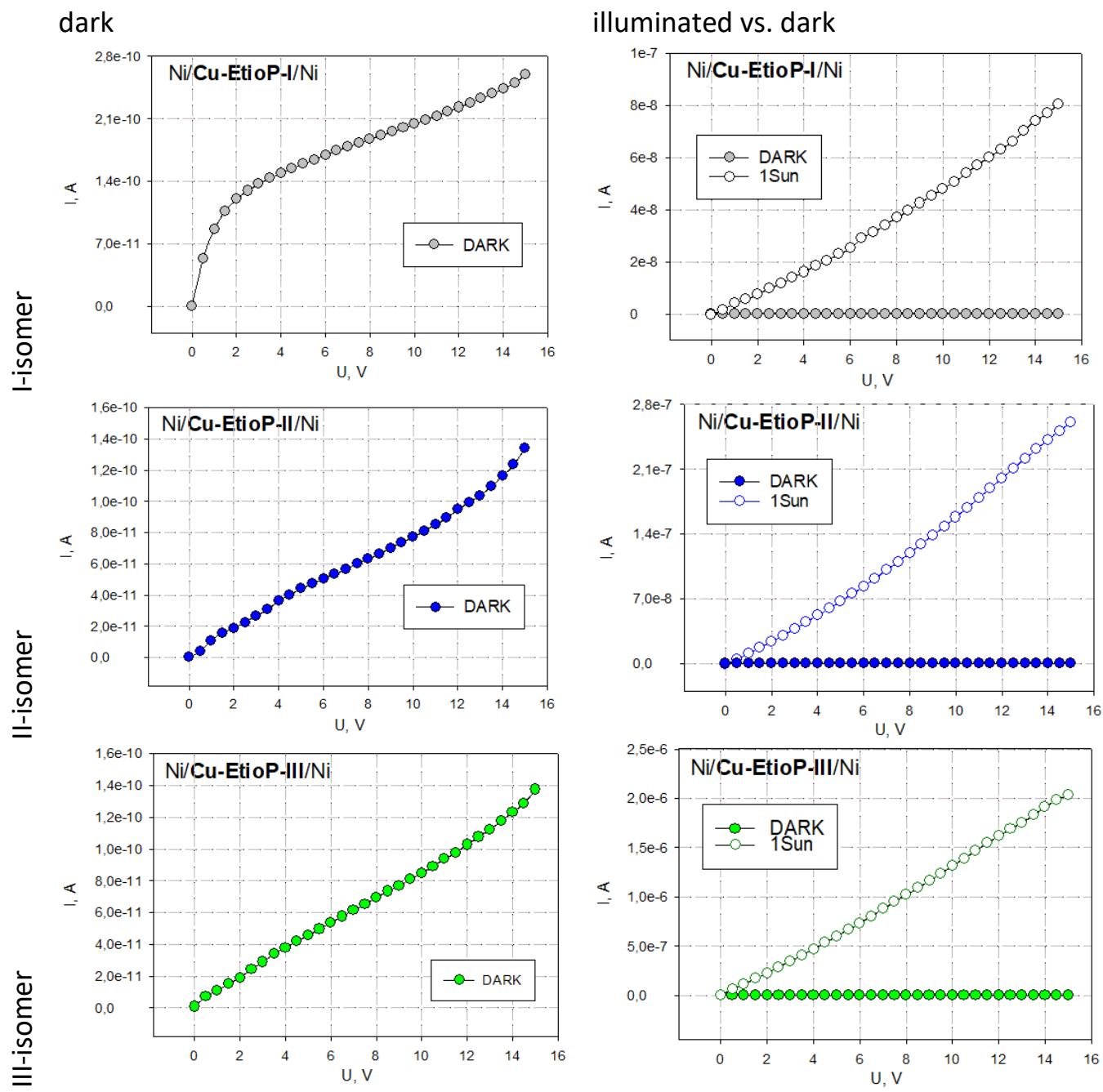
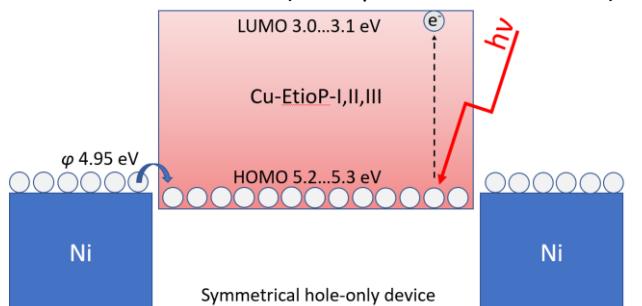


Figure S7

Dark and illuminated I-V dependences measured at room temperature in air-free conditions for three Cu-EtioP isomers vacuum-deposited on the substrates with IDE contacts shown in Fig. S6.



The tentative band diagram of the device, the HOMO-LUMO values are estimated from CV (to be published elsewhere)



Example of an Arrhenius plot for the Cu-EtioP-II film →

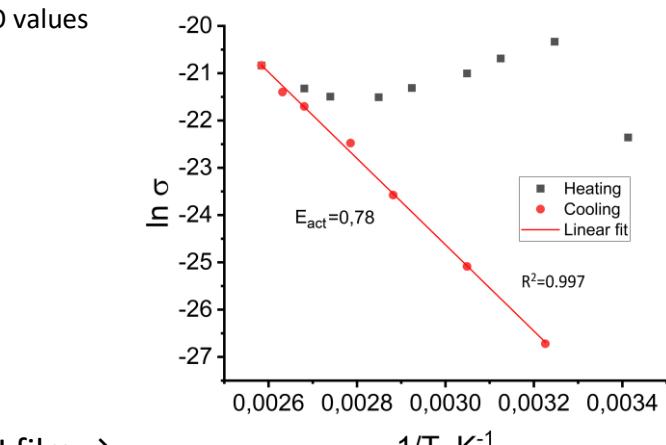


Table S1**Crystal data, details of data collection, and parameters of structure refinement**

Parameter	Value
Formula	C ₃₂ H ₃₄ CuN ₄
CCDC	2201607
M	538.17
System, Z	monoclinic, 2
Space group	P 2 ₁ /c
T, K	100(2)
a, Å	4.6803(6)
b, Å	20.039(2)
c, Å	14.846(2)
α, °	90
β, °	108.483(14)
γ, °	90
V, Å ³	1320.6(3)
D _x , g·cm ⁻³	1.353
μ, mm ⁻¹	0.855
Absorption T T _{min} /T _{max}	0.443 / 1.000
Absorption correction	Gaussian
F(000)	566
Size, mm	0.514 × 0.065 × 0.044
Diffractometer / Radiation / Monochromator / Scan	Rigaku XtaLab, MM003, P200K / MoKα, λ= 0.71073 Å / MicroMax-003 / ω scans
Range of θ, °	4.318 - 26.371
Range of indices	-5 ≤ h ≤ 5 -25 ≤ k ≤ 25 -18 ≤ l ≤ 18
Measured reflections, all / independent / with I > 2σ(I) / R _{int}	10915 / 2546 / 1230 / 0.1626
Parameters	185
GOOF	0.956
R-factors for F ² > 2 σ(F ²)	R ₁ = 0.0929 wR ₂ = 0.1935
R-factors for all reflexes	R ₁ = 0.1807 wR ₂ = 0.2254
Δρ(min/max), e·Å ⁻³	-0.494 / 1.223

Table S2**The atom list for C₃₂H₃₄CuN₄**

Atom	x	y	z	Occupancy	Ueq, Å ²
C1	0.8358(16)	0.4550(4)	0.2929(5)	1	0.0435(18)
C2	0.6471(16)	0.4055(3)	0.3054(5)	1	0.049(2)
C3	0.5892(14)	0.3906(3)	0.3891(5)	1	0.0402(18)
C4	0.3894(16)	0.3387(3)	0.3987(5)	1	0.047(2)
C5	0.3883(15)	0.3400(4)	0.4889(6)	1	0.047(2)
C6	0.5868(15)	0.3927(3)	0.5367(5)	1	0.0422(18)
C7	0.6521(15)	0.4108(3)	0.6306(5)	1	0.0425(18)
C8	0.8454(16)	0.4613(4)	0.6779(5)	1	0.0417(18)
C9	0.9123(18)	0.4779(4)	0.7771(5)	1	0.052(2)
C10	1.1054(18)	0.5294(4)	0.7949(5)	1	0.051(2)
C11	1.236(2)	0.5670(4)	0.8882(5)	1	0.076(3)
C12	0.789(2)	0.4414(4)	0.8457(5)	1	0.064(2)

C13	0.955(3)	0.3817(6)	0.8854(7)	0.833(3)	0.093(4)
C14	0.2243(16)	0.2945(4)	0.5361(5)	1	0.053(2)
C15	0.418(3)	0.2372(6)	0.5794(9)	0.658(3)	0.068(4)
C16	0.2266(17)	0.2894(3)	0.3221(5)	1	0.053(2)
C17	0.379(4)	0.2288(10)	0.3160(13)	0.509(3)	0.101(7)
Cu1	1.000000	0.500000	0.500000	1	0.0413(4)
H2	0.547209	0.379077	0.251482	1	0.059
H7	0.554435	0.386088	0.666942	1	0.051
H11A	1.452215	0.573814	0.900826	1	0.113
H11B	1.203025	0.541021	0.940024	1	0.113
H11C	1.135560	0.610408	0.883878	1	0.113
H12A	0.790378	0.472004	0.898233	1	0.077
H12B	0.576340	0.429127	0.812441	1	0.077
H13A	0.829286	0.353012	0.911070	0.833(3)	0.139
H13B	1.138231	0.393971	0.936429	0.833(3)	0.139
H13C	1.008543	0.357623	0.835669	0.833(3)	0.139
H14A	0.168591	0.319323	0.585686	1	0.063
H14B	0.036913	0.278231	0.488609	1	0.063
H15A	0.301861	0.204937	0.603017	0.658(3)	0.102
H15B	0.590088	0.252909	0.632177	0.658(3)	0.102
H15C	0.491780	0.215786	0.531552	0.658(3)	0.102
H16A	0.033061	0.277750	0.331916	1	0.064
H16B	0.177958	0.312317	0.259955	1	0.064
H17A	0.290638	0.209330	0.252679	0.509(3)	0.152
H17B	0.357833	0.197412	0.364069	0.509(3)	0.152
H17C	0.592844	0.238099	0.327009	0.509(3)	0.152
N1	0.7100(12)	0.4241(3)	0.4729(4)	1	0.0410(15)
N2	1.0016(11)	0.5018(3)	0.6357(4)	1	0.0444(14)

Table S3
Interatomic distances for C₃₂H₃₄CuN₄

Atoms	Distance, Å	Atoms	Distance, Å	Atoms	Distance, Å
Cu1 – N1	1.993(5)	C6 – C5	1.437(10)	C14 – C15	1.479(12)
Cu1 – N1 ^(I)	1.993(5)	C8 – N2	1.370(9)	C14 – C5	1.500(10)
Cu1 – N2	2.013(6)	C8 – C7	1.390(9)	C9 – C10	1.342(10)
Cu1 – N2 ^(I)	2.013(6)	C8 – C9	1.444(9)	C9 – C12	1.511(10)
C3 – N1	1.368(8)	C1 – C2	1.379(10)	C10 – C11	1.525(10)
C3 – C2	1.386(10)	C1 ^(I) – N2	1.392(8)	C12 – C13	1.446(12)
C3 – C4	1.434(10)	C1 – C10 ^(I)	1.449(10)	C16 – C17	1.425(19)
C6 – C7	1.377(9)	C4 – C5	1.341(10)		
C6 – N1	1.405(9)	C4 – C16	1.518(9)		

Symmetry codes: I) -x+2, -y+1, -z+1;

Table S4

Valence angles for C₃₂H₃₄CuN₄

Atoms	Angle, °	Atoms	Angle, °	Atoms	Angle, °
N1 ^(I) – Cu1 – N2	89.9(2)	C2 – C1 – C10 ^(I)	126.1(7)	N2 – C8 – C7	123.8(7)
N1 – Cu1 – N2 ^(I)	89.9(2)	N1 – C3 – C4	111.1(7)	C7 – C8 – C9	125.4(7)
N1 – Cu1 – N2	90.1(2)	C2 – C3 – C4	124.3(7)	C10 – C9 – C8	107.0(7)
N1 ^(I) – Cu1 – N2 ^(I)	90.1(2)	N1 – C3 – C2	124.5(7)	C8 – C9 – C12	124.8(8)
N1 – Cu1 – N1 ^(I)	180.0(2)	C5 – C4 – C3	107.1(6)	C10 – C9 – C12	128.1(7)
N2 – Cu1 – N2 ^(I)	180.0	C3 – C4 – C16	125.9(7)	C9 – C10 – C1 ^(I)	107.3(7)
C3 – N1 – C6	104.6(6)	C5 – C4 – C16	126.9(7)	C1 ^(I) – C10 – C11	125.1(8)
C6 – N1 – Cu1	127.2(5)	C4 – C5 – C6	107.5(7)	C9 – C10 – C11	127.6(8)

C3 – N1 – Cu1	128.1(5)	C6 – C5 – C14	124.2(7)	C1 – C2 – C3	126.3(6)
C8 – N2 – C1 ⁽ⁱ⁾	105.3(6)	C4 – C5 – C14	128.3(7)	C6 – C7 – C8	127.1(7)
C1 ⁽ⁱ⁾ – N2 – Cu1	126.9(5)	N1 – C6 – C5	109.6(6)	C13 – C12 – C9	113.8(8)
C8 – N2 – Cu1	127.8(5)	C7 – C6 – N1	123.9(7)	C15 – C14 – C5	109.9(7)
N2 ⁽ⁱ⁾ – C1 – C10 ⁽ⁱ⁾	109.6(7)	C7 – C6 – C5	126.5(7)	C17 – C16 – C4	117.4(9)
C2 – C1 – N2 ⁽ⁱ⁾	124.3(7)	N2 – C8 – C9	110.8(7)		

Symmetry codes: I) -x+2, -y+1, -z+1;